

Adenilson J Chiquito

List of Publications by Year in descending order

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111
papers

1,432
citations

430874

18
h-index

395702

33
g-index

111
all docs

111
docs citations

111
times ranked

1831
citing authors

#	ARTICLE	IF	CITATIONS
1	Structural characterization of indium oxide nanostructures: a Raman analysis. <i>Journal Physics D: Applied Physics</i> , 2010, 43, 045401.	2.8	148
2	Back-to-back Schottky diodes: the generalization of the diode theory in analysis and extraction of electrical parameters of nanodevices. <i>Journal of Physics Condensed Matter</i> , 2012, 24, 225303.	1.8	122
3	Sb doping of VLS synthesized SnO ₂ nanowires probed by Raman and XPS spectroscopy. <i>Chemical Physics Letters</i> , 2018, 695, 125-130.	2.6	97
4	Characterization of BaTi _{1-x} Zr _x O ₃ thin films obtained by a soft chemical spin-coating technique. <i>Journal of Applied Physics</i> , 2004, 96, 4386-4391.	2.5	63
5	Influence of Ca concentration on the electric, morphological, and structural properties of (Pb,Ca)TiO ₃ thin films. <i>Journal of Applied Physics</i> , 2002, 91, 6650.	2.5	57
6	Capacitance-voltage profile in a structure with negative differential capacitance caused by the presence of InAs/GaAs self-assembled quantum dots. <i>Physical Review B</i> , 2000, 61, 5499-5504.	3.2	48
7	Electron Dephasing and Weak Localization in Sn Doped In ₂ O ₃ Nanowires. <i>Nano Letters</i> , 2007, 7, 1439-1443.	9.1	43
8	Investigation of phase transition in ferroelectric Pb _{0.70} Sr _{0.30} TiO ₃ thin films. <i>Journal of Applied Physics</i> , 2004, 96, 1192-1196.	2.5	36
9	Structural and ferroelectric properties of Pb _{1-x} Sr _x TiO ₃ thin films. <i>Applied Physics A: Materials Science and Processing</i> , 2005, 80, 875-880.	2.3	30
10	Electron transport properties of undoped SnO ₂ monocrystals. <i>Journal of Applied Physics</i> , 2009, 105, 023708.	2.5	29
11	Synthesis and characterization of ZrO ₂ @SiO ₂ core-shell nanostructure as nanocatalyst: Application for environmental remediation of rhodamine B dye aqueous solution. <i>Materials Chemistry and Physics</i> , 2019, 233, 1-8.	4.0	28
12	Electrical Properties of Highly Conducting SnO ₂ :Sb Nanocrystals Synthesized using a Nonaqueous Sol-Gel Method. <i>Journal of the American Ceramic Society</i> , 2010, 93, 3862-3866.	3.8	24
13	Silver-controlled evolution of morphological, structural, and optical properties of three-dimensional hierarchical WO ₃ structures synthesized from hydrothermal method. <i>Journal of Alloys and Compounds</i> , 2018, 736, 143-151.	5.5	24
14	Understanding the fundamental electrical and photoelectrochemical behavior of a hematite photoanode. <i>Physical Chemistry Chemical Physics</i> , 2016, 18, 21780-21788.	2.8	22
15	Influence of Synthesis Time on the Morphology and Properties of CeO ₂ Nanoparticles: An Experimental-Theoretical Study. <i>Crystal Growth and Design</i> , 2020, 20, 5031-5042.	3.0	22
16	An alternative chemical route for synthesis of SrBi ₂ Ta ₂ O ₉ thin films. <i>Journal of Materials Research</i> , 2000, 15, 2091-2095.	2.6	21
17	Metal to insulator transition in Sb doped SnO ₂ monocrystalline nanowires thin films. <i>Journal of Applied Physics</i> , 2016, 120, .	2.5	21
18	Capacitance spectroscopy of InAs self-assembled quantum dots embedded in a GaAs/AlAs superlattice. <i>Journal of Applied Physics</i> , 2000, 88, 1987-1991.	2.5	20

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19	Parallel conductivity of random GaAs/AlGaAs superlattices in regime of controlled vertical disorder. Journal of Applied Physics, 2002, 92, 3830-3834.	2.5	18
20	Electrical conduction mechanism and phase transition studies using dielectric properties and Raman spectroscopy in ferroelectric Pb _{0.76} Ca _{0.24} TiO ₃ thin films. Journal of Applied Physics, 2003, 94, 7256-7260.	2.5	18
21	Sn ₃ O ₄ single crystal nanobelts grown by carbothermal reduction process. Journal of Crystal Growth, 2010, 312, 2881-2886.	1.5	18
22	Computational Chemistry Meets Experiments for Explaining the Geometry, Electronic Structure, and Optical Properties of Ca ₁₀ V ₆ O ₂₅ . Inorganic Chemistry, 2018, 57, 15489-15499.	4.0	18
23	One-step controllable synthesis of three-dimensional WO ₃ hierarchical architectures with different morphologies decorated with silver nanoparticles: enhancing the photocatalytic activity. RSC Advances, 2020, 10, 6625-6639.	3.6	18
24	One-dimensional character of miniband transport in doped GaAs/AlAs superlattices. Physical Review B, 1997, 56, 3892-3896.	3.2	17
25	Effect of inhomogeneous Schottky barrier height of SnO ₂ nanowires device. Semiconductor Science and Technology, 2018, 33, 055003.	2.0	17
26	Absence of relaxor-like ferroelectric phase transition in (Pb,Sr)TiO ₃ thin films. Applied Physics A: Materials Science and Processing, 2005, 80, 813-817.	2.3	15
27	Magnetoresistance in Sn-Doped In ₂ O ₃ Nanowires. Nanoscale Research Letters, 2009, 4, 921-5.	5.7	15
28	Synthesis, characterization, photocatalytic, and antimicrobial activity of ZrO ₂ nanoparticles and Ag@ZrO ₂ nanocomposite prepared by the advanced oxidative process/hydrothermal route. Journal of Sol-Gel Science and Technology, 2021, 98, 113-126.	2.4	15
29	Structural and electrical properties of LaNiO ₃ thin films grown on (100) and (001) oriented SrLaAlO ₄ substrates by chemical solution deposition method. Ceramics International, 2013, 39, 8025-8034.	4.8	14
30	Effect of Fe-doping on the structural, microstructural, optical, and ferroelectric properties of Pb _{1/2} Sr _{1/2} Ti _{1-x} Fe _x O ₃ oxide prepared by spin coating technique. Materials Letters, 2015, 138, 179-183.	2.6	14
31	A Raman and dielectric study of a diffuse phase transition in (Pb _{1-x} Ca _x)TiO ₃ thin films. Applied Physics A: Materials Science and Processing, 2004, 78, 349-354.	2.3	12
32	Electrical characterization of SnO ₂ :Sb ultrathin films obtained by controlled thickness deposition. Journal of Applied Physics, 2007, 102, .	2.5	12
33	Development of individual semiconductor nanowire for bioelectrochemical device at low overpotential conditions. Electrochemistry Communications, 2009, 11, 1744-1747.	4.7	12
34	Characterization of dense lead lanthanum titanate ceramics prepared from powders synthesized by the oxidant peroxy method. Materials Chemistry and Physics, 2010, 124, 1051-1056.	4.0	12
35	Disorder induced interface states and their influence on the Al/Ge nanowires Schottky devices. Journal of Applied Physics, 2013, 114, .	2.5	12
36	Investigation of trapping levels in p-type Zn ₃ P ₂ nanowires using transport and optical properties. Applied Physics Letters, 2018, 112, 193103.	3.3	12

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37	Growth and electrical characterization of semiconducting Ge nanowires. <i>Physica E: Low-Dimensional Systems and Nanostructures</i> , 2012, 44, 1776-1779.	2.7	11
38	Fluorine doped SnO ₂ (FTO) nanobelts: some data on electronic parameters. <i>Journal Physics D: Applied Physics</i> , 2014, 47, 045301.	2.8	11
39	Reliable Tin dioxide based nanowire networks as ultraviolet solar radiation sensors. <i>Sensors and Actuators A: Physical</i> , 2020, 302, 111825.	4.1	11
40	Effect of photogenerated holes on capacitance-voltage measurements in InAs/GaAs self-assembled quantum dots. <i>Physical Review B</i> , 2000, 61, 4481-4484.	3.2	10
41	Structural, optical, magnetic, ferroelectric, and piezoelectric properties of (Pb,Ba)(Ti,Fe)O ₃ perovskites: a macroscopic and nanoscale properties approach. <i>Journal of Materials Chemistry C</i> , 2016, 4, 9331-9342.	5.5	10
42	Carrier confinement in an ultrathin barrier GaAs/AlAs superlattice probed by capacitance-voltage measurements. <i>Physica E: Low-Dimensional Systems and Nanostructures</i> , 2002, 13, 36-42.	2.7	9
43	Electron-phonon scattering in Sn-doped In ₂ O ₃ FET nanowires probed by temperature-dependent measurements. <i>Nanotechnology</i> , 2009, 20, 245706.	2.6	9
44	Weak localization and electron-electron scattering in fluorine-doped SnO ₂ random nanobelt thin films. <i>Journal of Physics and Chemistry of Solids</i> , 2014, 75, 583-587.	4.0	9
45	Deposition of Controlled Thickness Ultrathin SnO ₂ :Sb Films by Spin-Coating. <i>Journal of Nanoscience and Nanotechnology</i> , 2006, 6, 3849-3853.	0.9	8
46	Electron-electron scattering in Sn doped In ₂ O ₃ nanowires. <i>Physica E: Low-Dimensional Systems and Nanostructures</i> , 2008, 40, 449-451.	2.7	8
47	Influence of a co-substituted A-site on structural characteristics and ferroelectricity of (Pb, Ba) _{1-x} (Tj, ET)Qq ₁ 1 0.784314 rgBT /Overlock 10 Science and Technology, 2014, 69, 605-616.	2.4	8
48	Transport properties of polycrystalline boron doped diamond. <i>Applied Surface Science</i> , 2014, 311, 5-8.	6.1	8
49	The interplay between Arrhenius and hopping conduction mechanisms in a percolating nanowire network. <i>Journal Physics D: Applied Physics</i> , 2016, 49, 315303.	2.8	8
50	Germanium nanowires grown using different catalyst metals. <i>Materials Chemistry and Physics</i> , 2016, 183, 145-151.	4.0	8
51	Influence of the metastable state (<i>i>V</i>++) on the electronic properties of SnO₂ nanowires under the influence of light. <i>Journal of Applied Physics</i>, 2020, 128, .</i>	2.5	8
52	Effect of hydrothermal temperature on the antibacterial and photocatalytic activity of WO ₃ decorated with silver nanoparticles. <i>Journal of Sol-Gel Science and Technology</i> , 2021, 97, 228-244.	2.4	8
53	Activation energies in diamond films evaluated using admittance spectroscopy and resistivity measurements. <i>Journal of Applied Physics</i> , 2007, 101, 033714.	2.5	7
54	Structural, microstructural, optical and electrical properties of (Pb,Ba,Sr)TiO ₃ films growth on conductive LaNiO ₃ -coated LaAO ₃ (100) and Pt/Ti/SiO ₂ /Si substrates. <i>Materials Letters</i> , 2014, 121, 93-96.	2.6	7

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55	The study of electron scattering mechanisms in single crystal oxide nanowires. Journal Physics D: Applied Physics, 2011, 44, 215405.	2.8	6
56	Measuring the mobility of single crystalline wires and its dependence on temperature and carrier density. Journal of Physics Condensed Matter, 2011, 23, 205803.	1.8	6
57	Structural, dielectric, ferroelectric and optical properties of PBCT, PBST and PCST complex thin films on LaNiO ₃ metallic conductive oxide layer coated Si substrates by the CSD technique. Journal of Alloys and Compounds, 2014, 609, 33-39.	5.5	6
58	Structural, ferroelectric, and optical properties of Pb _{0.60} Ca _{0.20} Sr _{0.20} TiO ₃ , Pb _{0.50} Ca _{0.25} Sr _{0.25} TiO ₃ and Pb _{0.40} Ca _{0.30} Sr _{0.30} TiO ₃ thin films prepared by the chemical solution deposition technique. Ceramics International, 2014, 40, 13363-13370.	4.8	6
59	Ferroelectric and structural instability of (Pb,Ca)TiO ₃ thin films prepared in an oxygen atmosphere and deposited on LSCO thin films which act as a buffer layer. Ceramics International, 2014, 40, 4085-4093.	4.8	6
60	Ferroelectric phase transition in Pb _{0.60} Sr _{0.40} TiO ₃ thin films. Materials Chemistry and Physics, 2004, 87, 353-356.	4.0	5
61	Temperature dependence of the electron distribution in a GaAs matrix with embedded InAs quantum dots. Physica E: Low-Dimensional Systems and Nanostructures, 2005, 25, 613-618.	2.7	5
62	A comparative study of p-type diamond films using Raman and transport measurements. Thin Solid Films, 2005, 476, 246-251.	1.8	5
63	Structural and morphological characterization of Pb _{1-x} BaxTiO ₃ thin films prepared by chemical route: An investigation of phase transition. Materials Chemistry and Physics, 2008, 108, 312-318.	4.0	5
64	Active-electrode biosensor of SnO ₂ nanowire for cyclodextrin detection from microbial enzyme. Nanotechnology, 2020, 31, 165501.	2.6	5
65	Effects of annealing on electrical and optical properties of a multilayer InAs/GaAs quantum dots system. Materials Research, 2004, 7, 459-465.	1.3	4
66	Controlling the optical properties of disordered GaAs/AlxGa _{1-x} As superlattices. Physical Review B, 2004, 69, .	3.2	4
67	Leakage current, ferroelectric and structural properties in Pb _{1-x} BaxTiO ₃ thin films prepared by chemical route. Journal of Physics and Chemistry of Solids, 2008, 69, 2796-2803.	4.0	4
68	Effect of strontium addition on ferroelectric phase transition of PZT thin films prepared by chemical route. Applied Physics A: Materials Science and Processing, 2009, 95, 693-698.	2.3	4
69	Detection of oxygen vacancy defect states in oxide nanobelts by using thermally stimulated current spectroscopy. Semiconductor Science and Technology, 2012, 27, 065021.	2.0	4
70	Grazing Angle Photoluminescence of Porous Alumina as an Analytical Transducer for Gaseous Ethanol Detection. Journal of Nanoscience and Nanotechnology, 2014, 14, 6653-6657.	0.9	4
71	Combined theoretical and nanoscale experimental study of Pb(Ca,Ba)TiO ₃ , Pb(Sr,Ba)TiO ₃ , and Pb(Sr,Ca)TiO ₃ complex perovskite structures: An investigation of the ferroelectric and electronic properties. Journal of Alloys and Compounds, 2017, 702, 327-337.	5.5	4
72	Nanoscale investigation of ferroelectric and piezoelectric properties in (Pb,Ca)TiO ₃ thin films grown on LaNiO ₃ /LaAlO ₃ (1 0 0) and Pt/Si(1 1 1) using piezoresponse force microscopy. Materials Letters, 2017, 196, 64-68.	2.6	4

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73	Direct evidence of traps controlling the carriers transport in SnO ₂ nanobelts. Journal of Semiconductors, 2017, 38, 122001.	3.7	4
74	Investigation of defects dependence of local piezoelectric response on Fe, La-modified (Pb,Sr)TiO ₃ thin films: A piezoresponse force microscopy study. Materials Chemistry and Physics, 2018, 214, 180-184.	4.0	4
75	The temperature dependence of electrical and optical properties in InAs/GaAs and GaAs/InAs/AlAs self-assembled quantum dots. Semiconductor Science and Technology, 2006, 21, 912-917.	2.0	3
76	Temperature sensors based on synthetic diamond films. Diamond and Related Materials, 2007, 16, 1652-1655.	3.9	3
77	Temperature dependence of electron properties of Sn doped nanobelts. Physica B: Condensed Matter, 2007, 400, 243-247.	2.7	3
78	Compressibility of electron liquid in the quantized Hall phase of GaAs/AlGaAs multi-layers. Physica E: Low-Dimensional Systems and Nanostructures, 2008, 40, 2682-2685.	2.7	3
79	Effects of strontium and calcium simultaneous substitution on electrical and structural properties of Pb _{1-x} Ca _x Sr _y TiO ₃ thin films. Applied Physics A: Materials Science and Processing, 2009, 96, 731-740.	2.3	3
80	Electrical properties of diamond films prepared from carbon disulfide and ethanol in hydrogen. Vacuum, 2010, 85, 180-183.	3.5	3
81	Investigation of the structural, optical and dielectric properties of highly (100)-oriented (Pb _{0.60} Ca _{0.20} Sr _{0.20})TiO ₃ thin films on LaNiO ₃ bottom electrode. Materials Science and Engineering B: Solid-State Materials for Advanced Technology, 2014, 185, 123-128.	3.5	3
82	A simple band model for ultraviolet induced ambipolarity in single SnO ₂ nanowire devices. Physica E: Low-Dimensional Systems and Nanostructures, 2021, 128, 114607.	2.7	3
83	A label-free Acetone based SnO ₂ nanowire network sensor at room temperature. Applied Physics A: Materials Science and Processing, 2022, 128, .	2.3	3
84	Plasma response of electrons in GaAs/AlAs superlattices in the presence of strong localization. Journal of Applied Physics, 2000, 88, 3093-3095.	2.5	2
85	Thermostabilization of Electrical Properties of InAs/GaAs Self-Assembled Quantum Dots Embedded in GaAs/AlAs Superlattices. Japanese Journal of Applied Physics, 2001, 40, 2006-2009.	1.5	2
86	Capacitance-voltage characteristics of InAs dots: a simple model. Brazilian Journal of Physics, 2002, 32, 784-789.	1.4	2
87	Pressure-induced electrical and structural anomalies in Pb _{1-x} Ca _x TiO ₃ thin films grown at various oxygen pressures by chemical solution route. Journal Physics D: Applied Physics, 2008, 41, 115402.	2.8	2
88	Electrical properties of SnO ₂ :Sb ultrathin films prepared by colloidal deposition process. Journal of Materials Research, 2016, 31, 148-153.	2.6	2
89	Annealing temperature dependence of local piezoelectric response of (Pb,Ca)TiO ₃ ferroelectric thin films. Ceramics International, 2017, 43, 5047-5052.	4.8	2
90	Direct preparation of standard functional interfaces in oxide heterostructures for 2DEG analysis through beam-induced platinum contacts. Applied Physics Letters, 2018, 113, .	3.3	2

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91	Photocurrent enhancement and magnetoresistance in indium phosphide single nanowire by zinc doping. <i>Journal Physics D: Applied Physics</i> , 2018, 51, 255106.	2.8	2
92	A New Possibility for Fermentation Monitoring by Electrical Driven Sensing of Ultraviolet Light and Glucose. <i>Biosensors</i> , 2020, 10, 97.	4.7	2
93	Effects of Annealing on Electrical Coupling in a Multilayer InAs/GaAs Quantum Dots System. <i>Japanese Journal of Applied Physics</i> , 2001, 40, 1882-1884.	1.5	1
94	Investigation of the InAs/GaAs self-assembled quantum dots using the relationship between the capacitance and the density of states. <i>Physica E: Low-Dimensional Systems and Nanostructures</i> , 2001, 9, 321-325.	2.7	1
95	INHOMOGENEITY OF ELECTRON LIQUID AND EFFECTS OF INTERLAYER COUPLING IN GaAs/AlGaAs SUPERLATTICES IN THE REGIME OF THE QUANTUM HALL EFFECT. <i>International Journal of Modern Physics B</i> , 2007, 21, 1409-1413.	2.0	1
96	Excitação dos modos normais de um sistema usando um motor desbalanceado. <i>Revista Brasileira De Ensino De Fisica</i> , 2007, 29, 5-10.	0.2	1
97	Investigation in SrTiO ₃ -CaTiO ₃ -PbTiO ₃ ternary thin films by dielectric proprieties and Raman spectroscopy. <i>Journal of Sol-Gel Science and Technology</i> , 2010, 55, 151-157.	2.4	1
98	Weak localization and quantum interference in Sn doped In ₂ O ₃ nanowires. <i>AIP Conference Proceedings</i> , 2010, , .	0.4	1
99	Gaussian distribution of Schottky barrier heights on SnO ₂ nanowires. <i>Materials Research Society Symposia Proceedings</i> , 2011, 1406, .	0.1	1
100	Surface States Influence in Al Schottky Barrier of Ge Nanowires. <i>Materials Research Society Symposia Proceedings</i> , 2013, 1510, 1.	0.1	1
101	Optical and transport properties correlation driven by amorphous/crystalline disorder in InP nanowires. <i>Journal of Physics Condensed Matter</i> , 2016, 28, 475303.	1.8	1
102	Metallic behavior in STO/LAO heterostructures with non-uniformly atomic interfaces. <i>Materials Today Communications</i> , 2020, 24, 101339.	1.9	1
103	Evidence of formation of an XLminiband in short-period type-II GaAs/AlAs superlattices. <i>Journal of Physics Condensed Matter</i> , 2002, 14, 9601-9605.	1.8	0
104	Influence of annealing on the optical and electrical properties of multilayered InAs/GaAs quantum dots. <i>Brazilian Journal of Physics</i> , 2002, 32, 287-289.	1.4	0
105	Carrier confinement in disordered GaAs/AlAs superlattices probed by capacitance-voltage experiments. <i>Physica E: Low-Dimensional Systems and Nanostructures</i> , 2005, 30, 69-73.	2.7	0
106	Reply to "Comment on "Electron-phonon scattering in Sn-doped In ₂ O ₃ FET nanowires probed by temperature-dependent measurements". <i>Nanotechnology</i> , 2009, 20, 468002.	2.6	0
107	Synthesis and Electrical Characterization of Tin Oxide Nanostructures. <i>Materials Research Society Symposia Proceedings</i> , 2009, 1178, 74.	0.1	0
108	Schottky contacts in germanium nanowire network devices synthesized from nickel seeds. <i>Physica E: Low-Dimensional Systems and Nanostructures</i> , 2016, 84, 537-542.	2.7	0

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109	A Study of Visible-Blind Properties of a SnO ₂ ™s Nanowires Network Photodetector. Engineering Proceedings, 2021, 6, .	0.4	0
110	Super-redes semicondutoras: um laboratÃ³rio de MecÃ¢nica QuÃ¢ntica. Revista Brasileira De Ensino De Fisica, 2004, 26, 315-322.	0.2	0
111	CÃ©lulas solares "caseiras". Revista Brasileira De Ensino De Fisica, 2004, 26, .	0.0	0